TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

# **SM2G54,SM2L54**

### AC POWER CONTROL APPLICATIONS

Repetitive Peak Off-State Voltage : V<sub>DRM</sub> = 800V
 R.M.S. On-State Current : I<sub>T</sub> (RMS) = 2A

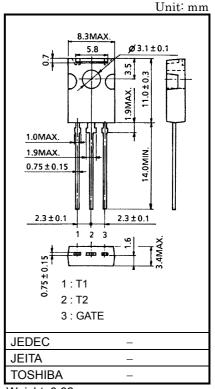
• High Commutation (dv / dt) :  $(dv / dt) c = 5V / \mu s$  (Min.)

### **MAXIMUM RATINGS**

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage	$V_{DRM}$	800	V	
R.M.S. On-State Current (Full Sine Waveform)	I <sub>T (RMS)</sub>	2	Α	
Peak One Cycle Surge On-State	l	8 (50Hz)	Α	
Current (Non-Repetitive)	ITSM	8.8 (60Hz)	_ ^	
I <sup>2</sup> t Limit Value	I <sup>2</sup> t	0.32	A <sup>2</sup> s	
Critical Rate of Rise of On-State Current (Note)	di / dt	50	A / μs	
Peak Gate Power Dissipation	P <sub>GM</sub>	3	W	
Average Gate Power Dissipation	P <sub>G (AV)</sub>	0.3	W	
Peak Gate Voltage	$V_{FGM}$	10	V	
Peak Gate Current	I <sub>GM</sub>	1.6	Α	
Junction Temperature	Tj	-40~125	°C	
Storage Temperature Range	T <sub>stg</sub>	-40~125	°C	

Note: di / dt test condition

 $V_{DRM}$  = 400V,  $I_{TM} \le 3A$ ,  $t_{gw} \ge 10\mu s$ ,  $t_{gr} \le 250ns$ ,  $i_{gp}$  =  $I_{GT} \times 2.0$ 

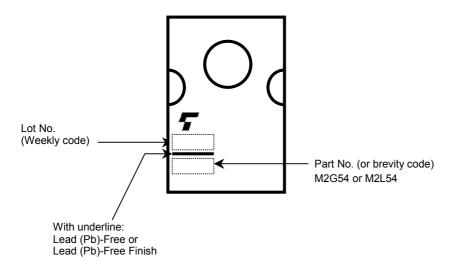


Weight: 0.82g

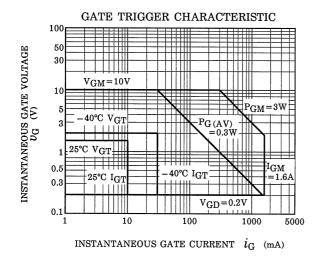
## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

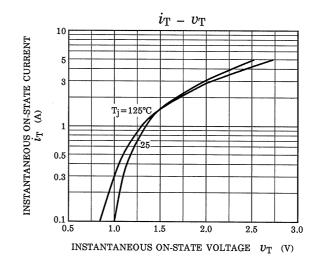
CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current		I <sub>DRM</sub>	V <sub>DRM</sub> = 800V		-	-	20	μΑ
Gate Trigger Voltage	I	V <sub>GT</sub>	V <sub>D</sub> = 12V, R <sub>L</sub> = 20Ω	T2 (+) , Gate (+)	-	-	1.5	V
	II			T2 (+) , Gate (−)	-	-	1.5	
	III			T2 (-) , Gate (-)	-	-	1.5	
Gate Trigger Current	I	l <sub>GT</sub>	V <sub>D</sub> = 12V, R <sub>L</sub> = 20Ω	T2 (+) , Gate (+)	-	-	10	mA
	II			T2 (+) , Gate (−)	-	-	10	
	III			T2 (-) , Gate (-)	-	-	10	
Peak On-State Voltage		V <sub>TM</sub>	I <sub>TM</sub> = 3A		-	-	2.0	٧
Gate Non-Trigger Voltage		$V_{GD}$	V <sub>D</sub> = 800V, Tc = 125°C		0.2	-	-	٧
Holding Current		lΗ	V <sub>D</sub> = 12V, I <sub>TM</sub> = 1A		-	-	10	mA
Thermal Resistance		R <sub>th (j−a)</sub>	Junction to Ambient, AC		-	-	83	°C/W
Critical Rate of Rise of Off-State Voltage		dv / dt	V <sub>DRM</sub> = 800V, T <sub>j</sub> = 125°C Exponential Rise		50	=	=	V / µs
Critical Rate of Rise of Off-State Voltage at Communication		(dv / dt) c	$V_{DRM}$ = 400V, $T_j$ = 80°C (di / dt) c = -0.5A / ms		5	-	-	V / µs

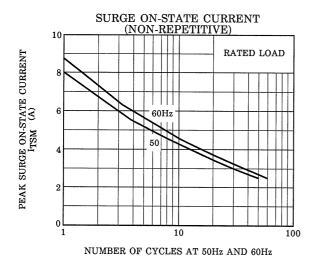
### **MARKING**

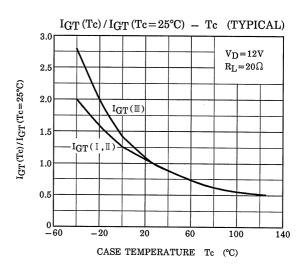


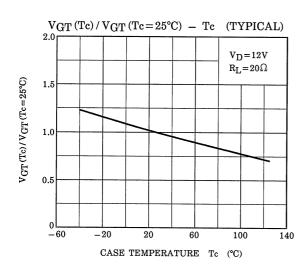
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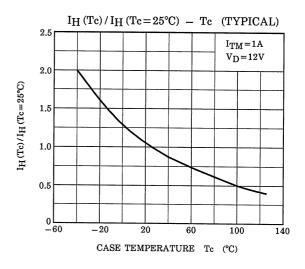




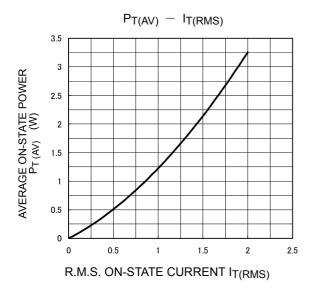


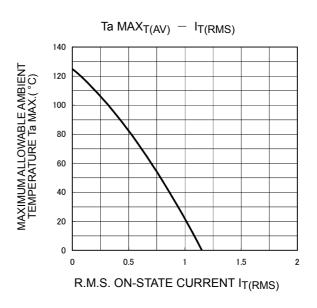


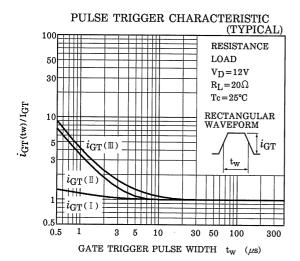


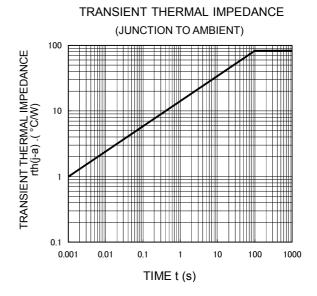


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